

## AXIAL LEADED HERMETICALLY SEALED SUPERFAST RECTIFIER DIODE

## QUICK REFERENCE DATA

- Very low reverse recovery time
- Glass passivated for hermetic sealing
- Low switching losses
- Soft, non-snap off, recovery characteristics
- Low forward voltage drop

- $V_R = 50 - 200V$
- $I_F = 2.6A$
- $t_{rr} = 25nS$
- $V_F = 0.97V$

### ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	2PFT05	2PFT1	2PFT15	2PFT2	Unit
Working reverse voltage	$V_{RWM}$	50	100	150	200	V
Repetitive reverse voltage	$V_{RRM}$	50	100	150	200	V
Average forward current (@ 55°C, lead length = 0.375")	$I_{F(AV)}$	← 2.6 →				A
Repetitive surge current (@ 55°C in free air, lead length 0.375")	$I_{FRM}$	← 15.0 →				A
Non-repetitive surge current ( $t_p = 8.3mS$ , @ $V_R$ & $T_{jmax}$ )	$I_{FSM}$	← 50.0 →				A
Storage temperature range	TSTG	← -65 to +175 →				°C
Operating temperature range	TOP	← -65 to +175 →				°C

### MECHANICAL

G88

DIM #	DIMENSIONS				NOTE
	MM		INCHES		
A	-	3.81	-	.150	-
B	28.0	-	1.10	-	-
C	-	4.57	-	.180	-
D	-	0.81	-	.032	-

Weight = 0.013oz

These products are qualified in Europe to DEF STAN 59-61 (PART 80)/043 available to F and FX levels.

January 7, 1998

**ELECTRICAL CHARACTERISTICS** (@ 25°C unless otherwise specified)

	Symbol	2PFT05	2PFT1	2PFT15	2PFT2	Unit
Average forward current max. (pcb mounted; T <sub>A</sub> = 55°C) for sine wave	I <sub>F(AV)</sub>	← 1.35 →				A
	I <sub>F(AV)</sub>	← 1.40 →				A
Average forward current max. (T <sub>L</sub> = 55°C ; L = 3/8") for sine wave	I <sub>F(AV)</sub>	← 2.4 →				A
	I <sub>F(AV)</sub>	← 2.6 →				A
I <sup>2</sup> t for fusing (t = 8.3mS) max.	I <sup>2</sup> t	← 10.6 →				A <sup>2</sup> S
Forward voltage drop max. @ I <sub>F</sub> = 2.0A, T <sub>j</sub> = 25°C	V <sub>F</sub>	← 0.97 →				V
Reverse current max. @ V <sub>RWM</sub> , T <sub>j</sub> = 25°C	I <sub>R</sub>	← 1.0 →				μA
	I <sub>R</sub>	← 10 →				μA
Reverse recovery time max. 0.5A I <sub>F</sub> to 1.0A I <sub>R</sub> . Recovers to 0.25A I <sub>RR</sub> .	t <sub>rr</sub>	← 25 →				nS
Junction capacitance typ. @ V <sub>R</sub> = 5V, f = 1MHz	C <sub>j</sub>	← 45 →				pF

**THERMAL CHARACTERISTICS**

	Symbol	2PFT05	2PFT1	2PFT15	2PFT2	Unit
Thermal resistance - junction to lead Lead length = 0.375"	R <sub>θJL</sub>	← 47 →				°C/W
	R <sub>θJL</sub>	← 19 →				°C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R <sub>θJA</sub>	← 100 →				°C/W

January 7, 1998

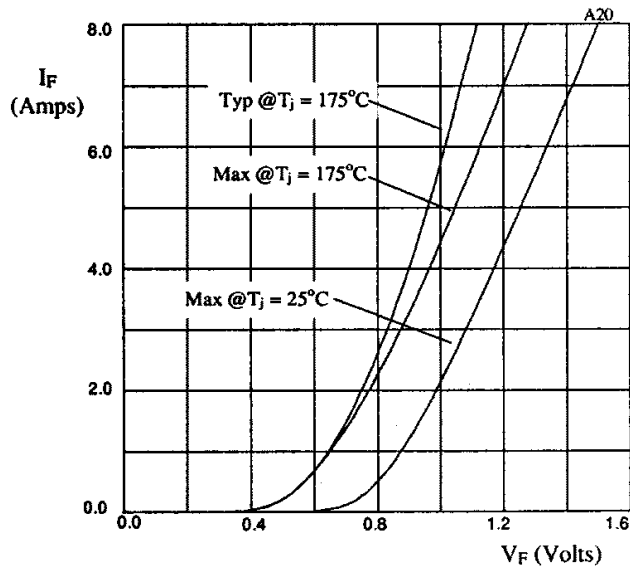


Fig 1. Forward voltage drops as a function of forward current.

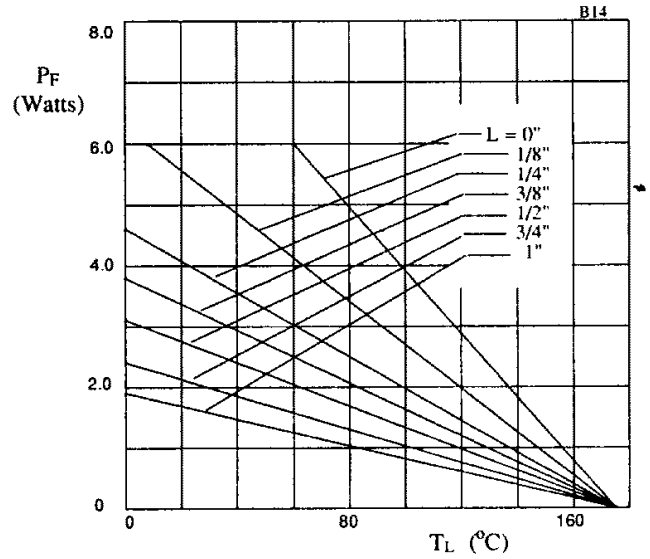


Fig 2. Maximum power versus lead temperature.

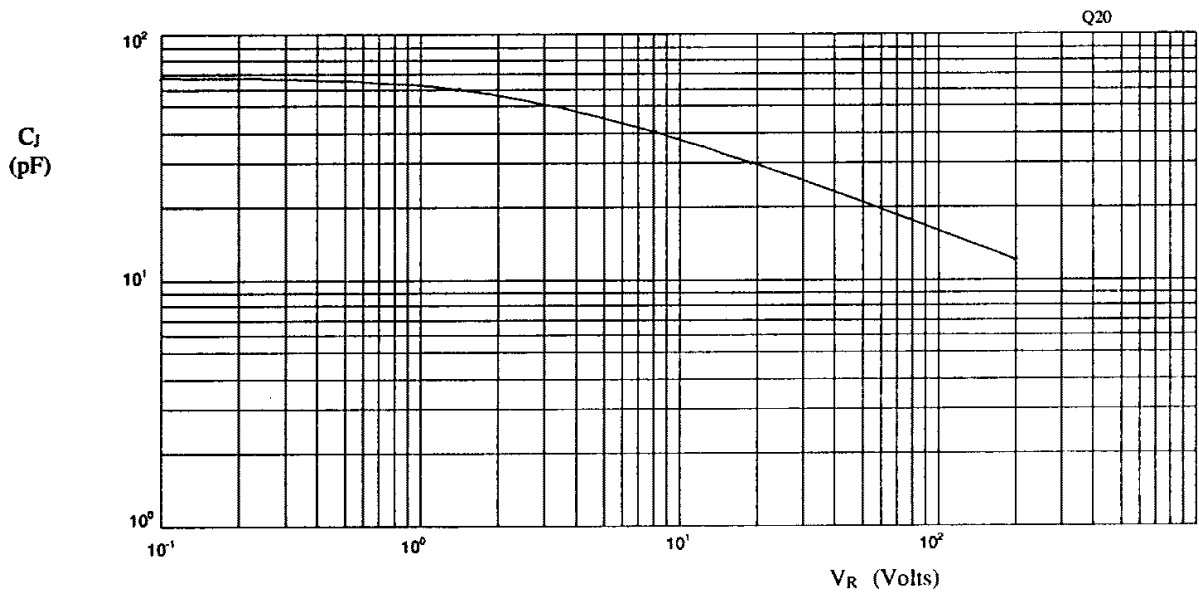


Fig 3. Typical junction capacitance as a function of reverse voltage.

January 7, 1998

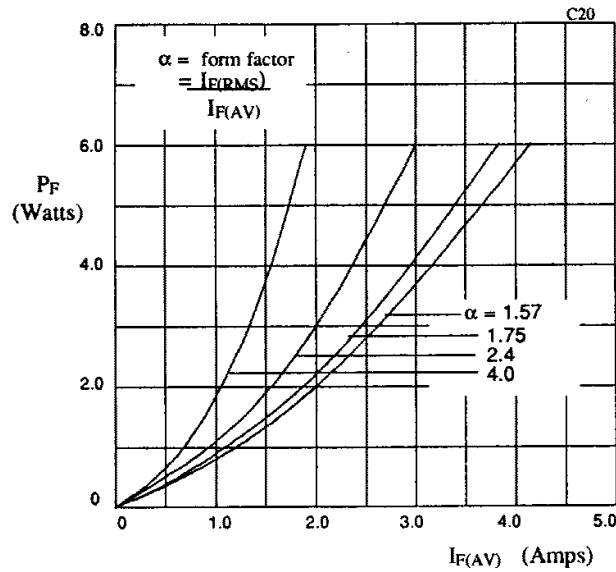


Fig 4. Forward power dissipation as a function of forward current, for sinusoidal operation.

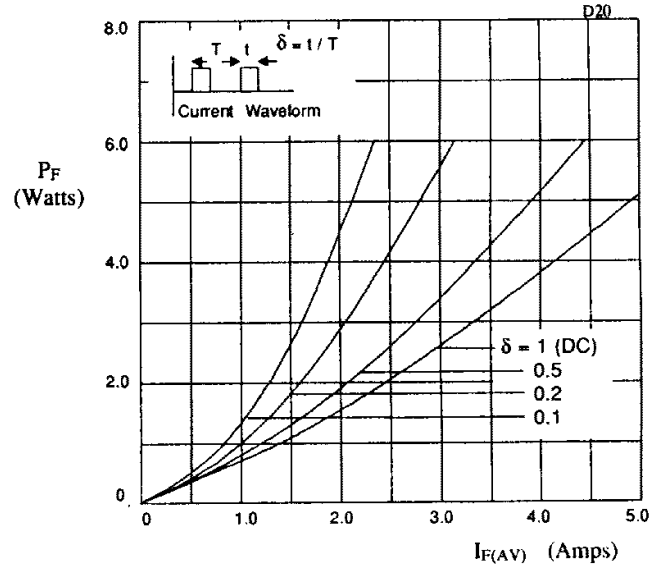


Fig 5. Forward power dissipation as a function of forward current, for square wave operation.

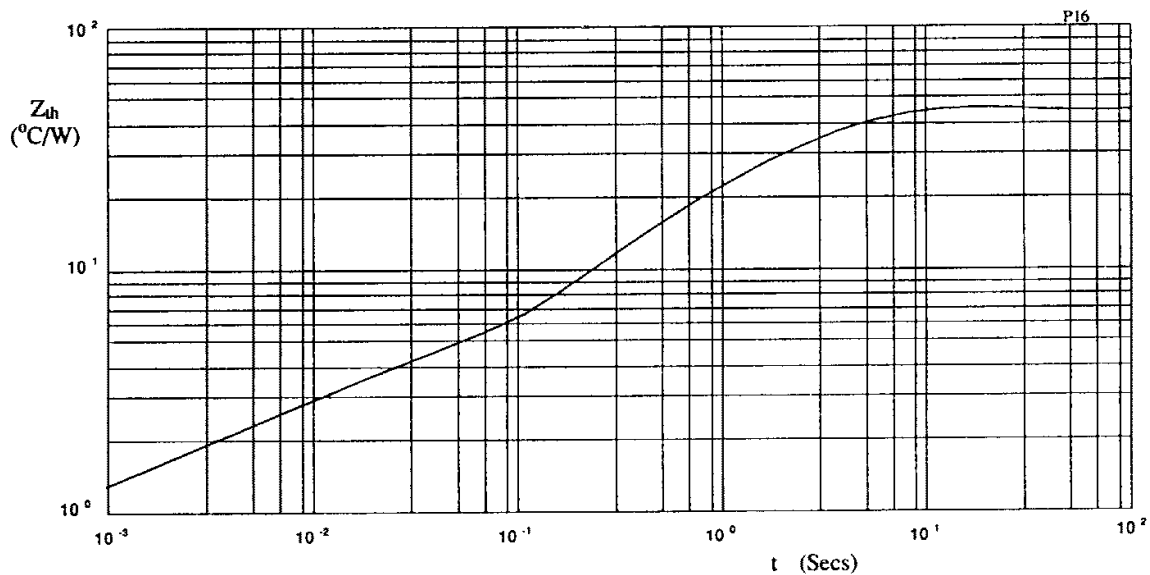


Fig 6. Transient thermal impedance characteristic.